

## RQ3E100MNTB1

### **RQ3E100MNTB1 Information**

Winnelsener.com	RQ3E100MNTB1 Rohm Semiconductor Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single MOSFET N-CH 30V 10A HSMT8 8-PowerVDFN For the pricing/inventory/lead time, please contact us	
For Reference Only	Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

#### **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



#### **RQ3E100MNTB1** Specifications

Manufacturer Part Number	RQ3E100MNTB1
Manufacturer	Rohm Semiconductor
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	8-PowerVDFN
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	10A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	2.5V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	9.9nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	520pF @ 15V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	2W (Ta)
Rds On (Max) @ Id, Vgs	12.3 mOhm @ 10A, 10V
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	8-HSMT (3.2x3)
Package / Case	8-PowerVDFN
	Report errors?

#### **RQ3E100MNTB1** Guarantees



Quality Guarantees

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

# SERVICE EUARANTEE

#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

#### **RQ3E100MNTB1** Payment Methods





If you have any question about RQ3E100MNTB1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com